File Name	
Sample (sample name, size, ink recipe,	
substrates, etc.)	
CNT materials (Synthesis & processing	
conditions)	
Variable 1 (Tam)	
Vacuum Level (Torr)	
Time Taken to Reach the Vacuum Level	
(hours)	
(nours)	
External Resistance (Ohm)	
Anode Voltage Range (V)	
Anode (anode materials, etc.)	
Timode (unode materials, etc.)	
Gate Voltage Range (V)	
Gate (gate materials, wire width, pitch size	
and transmission rate, etc.)	
Gap Distance between Anode and Gate	
Sup Distance setween 7 mode and Suite	
Gap Distance between Cathode and Gate	
D. C. D. A. L. C.	
Ratio Between Anode Current and Gate	
Current	
Duty Cycle	
Buty Cycle	
Pulse Frequency (Hz)	
D 1 W' 14 / \	
Pulse Width (ms)	
Turn-On Voltage (V)	
Maximum Current (mA)	

Image Name	
Corresponding File Name	
Sample (sample name, size, ink recipe, substrates, etc.)	
Field Emission Current at Capture (A)	
Anode Voltage at Capture (V)	
Gate Voltage at Capture (V)	
Duty Cycle	
Pulse Frequency (Hz)	
Pulse Width (ms)	

Suggested Measurement Parameters

Gap	1mm
Pulse Frequency (Hz)	100
Pulse Width	1 ms
Duty Cycle	10%
External Resistance (kohm)	100
Anode	Phosphor Screen
Anode Voltage (V)	Up to 2000
Gate Voltage (V)	150-300